

Supporting Information

Synthesis of hierarchical structured Fe₂O₃ rod clusters with numerous empty nanovoids via the Kirkendall effect and their electrochemical properties for lithium-ion storage

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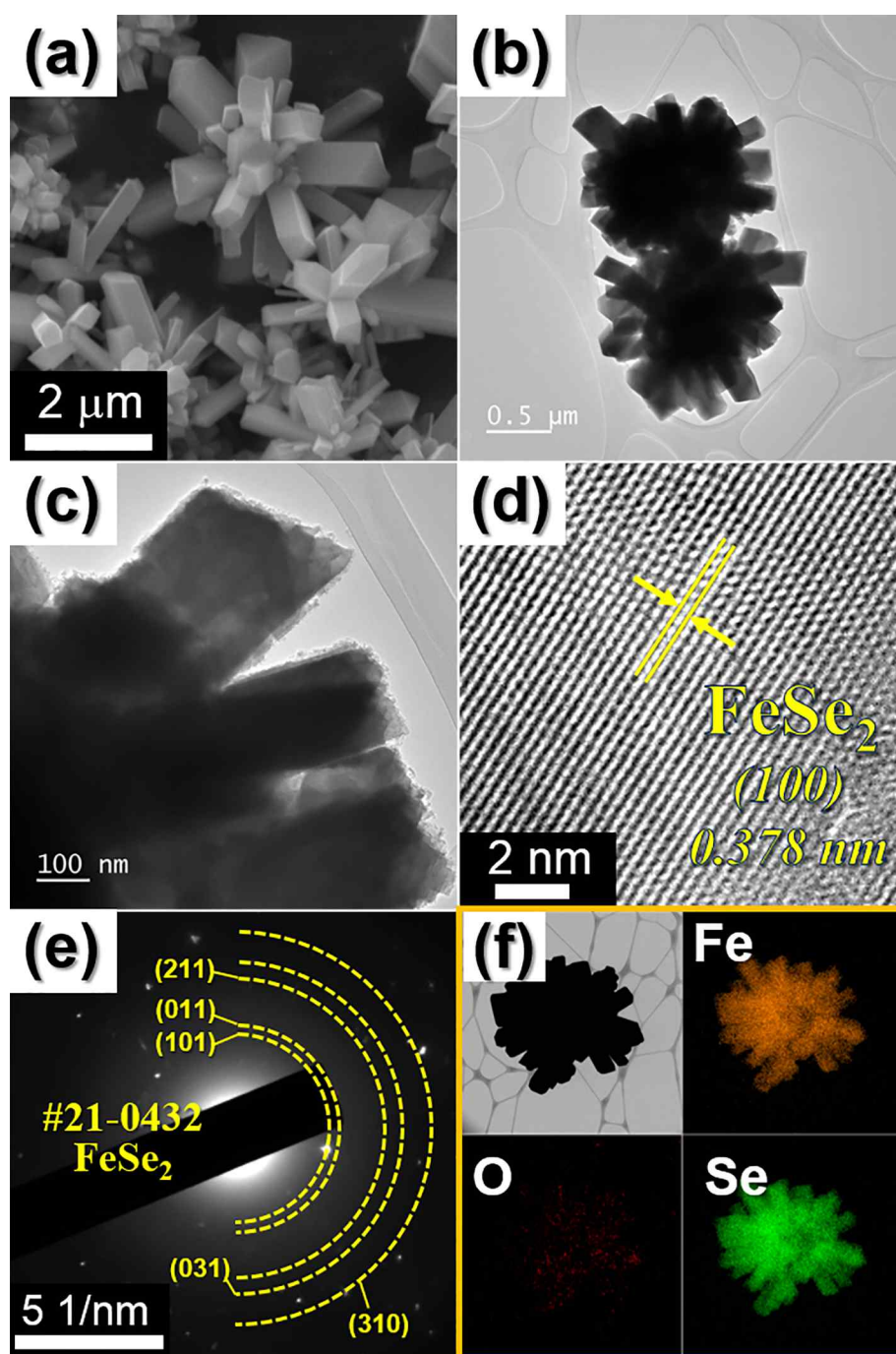


Fig. S1 Morphologies and crystal structure of FeSe_2 rod clusters: (a) SEM image, (b, c) TEM images, (d) HR-TEM image (e) SAED pattern, and (f) elemental mapping images.

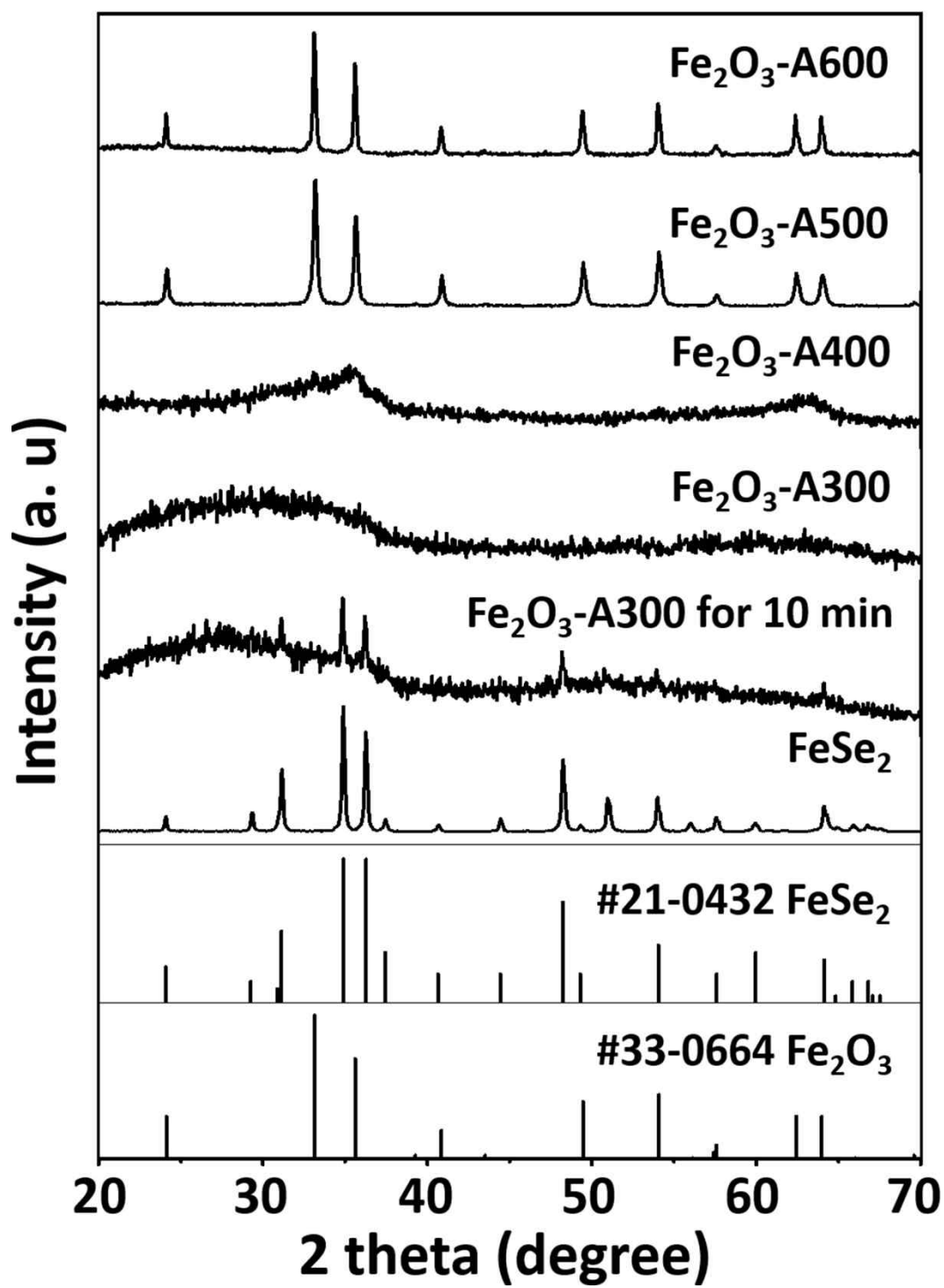


Fig. S2 XRD patterns of FeSe₂, Fe₂O₃-A300 oxidized for 10 min, and Fe₂O₃-A300, -A400, -A500, and -A600 rod clusters oxidized for 3 hrs.

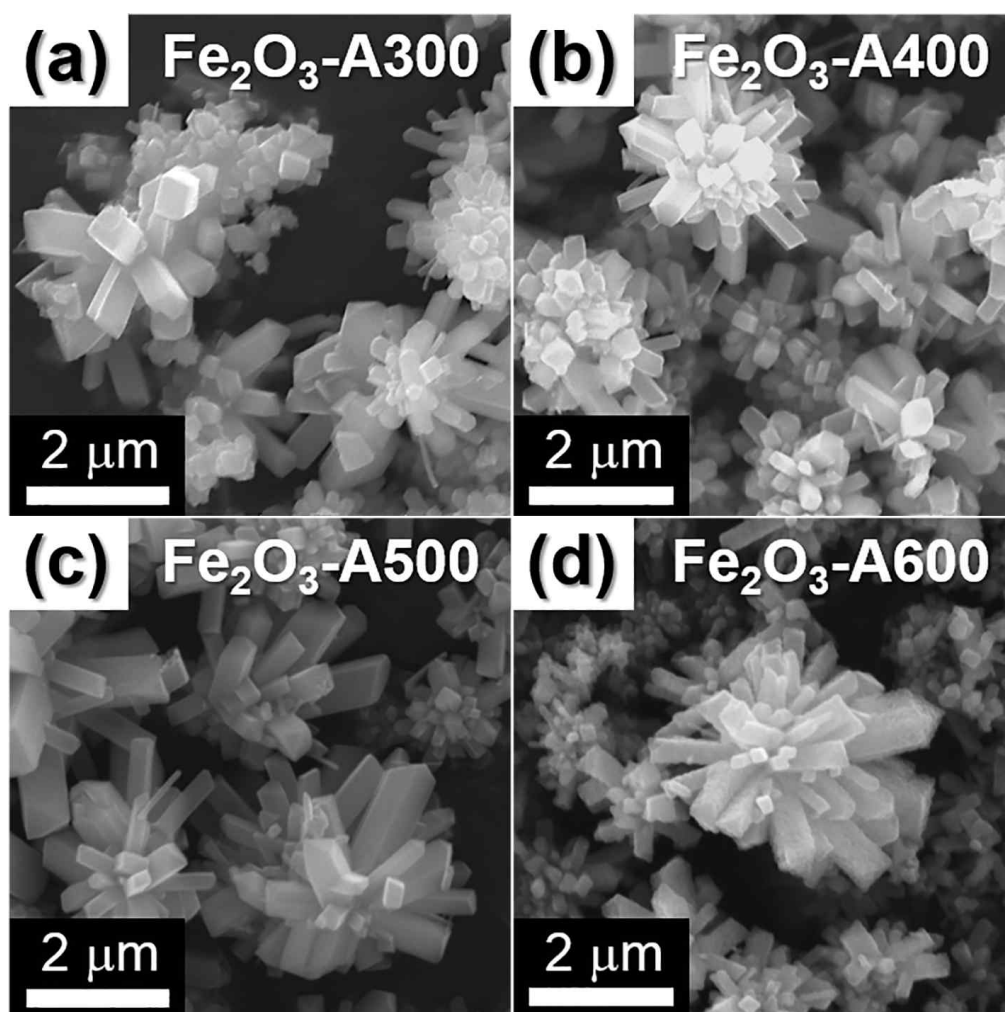


Fig. S3 SEM images of Fe₂O₃-A300, -A400, -A500, and -A600 rod clusters.

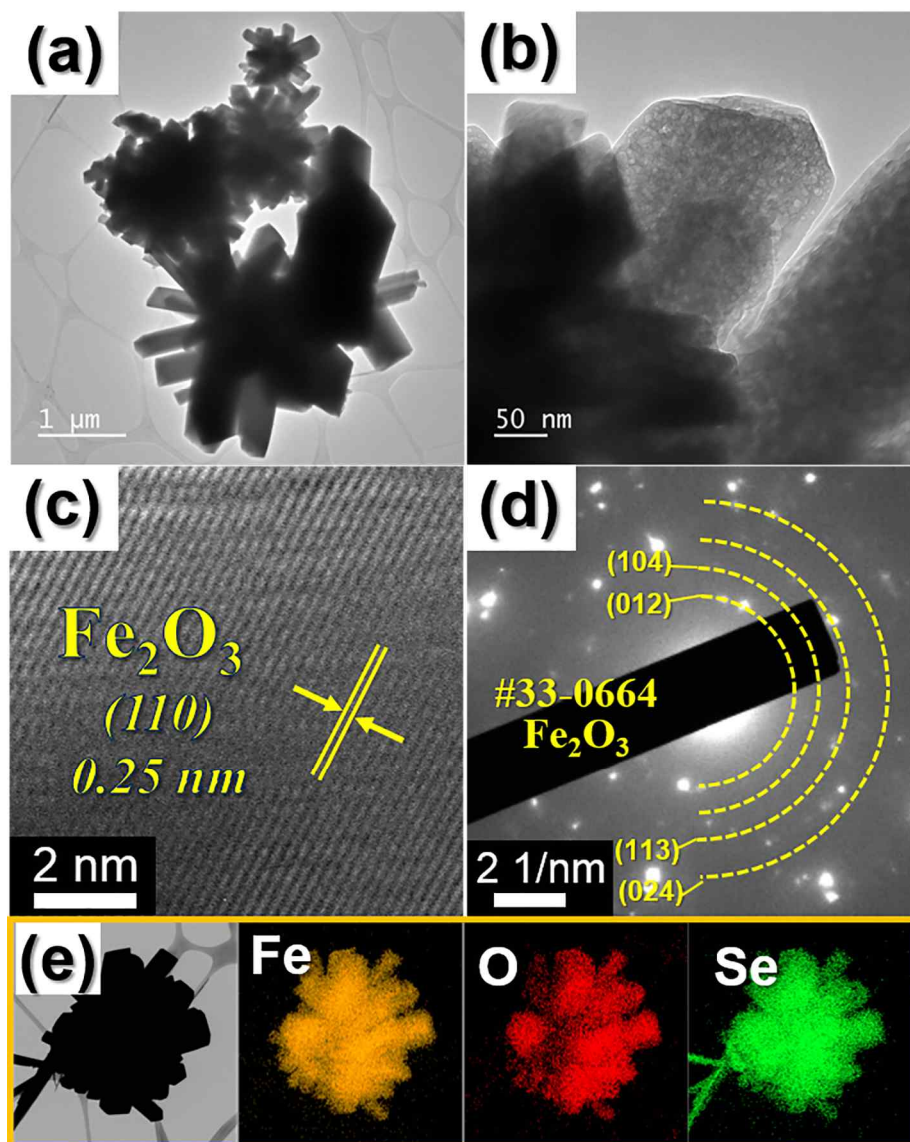


Fig. S4 Morphologies and crystal structure of Fe_2O_3 -A300 rod clusters: (a, b) TEM images, (c) HR-TEM image (d) SAED pattern, and (e) elemental mapping images.

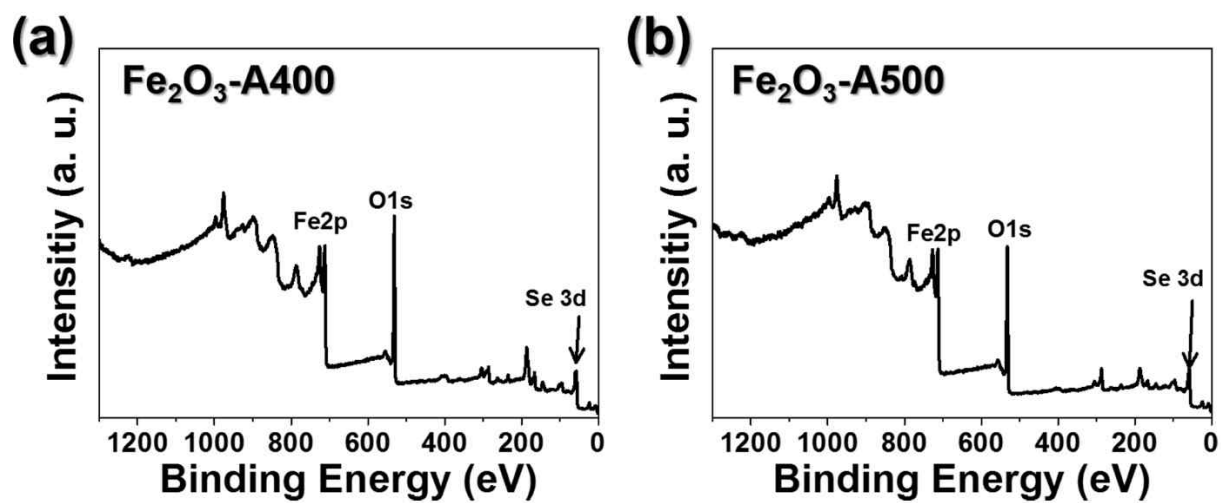


Fig. S5 XPS survey scan of (a) $\text{Fe}_2\text{O}_3\text{-A400}$ and (b) $\text{Fe}_2\text{O}_3\text{-A500}$ rod clusters.

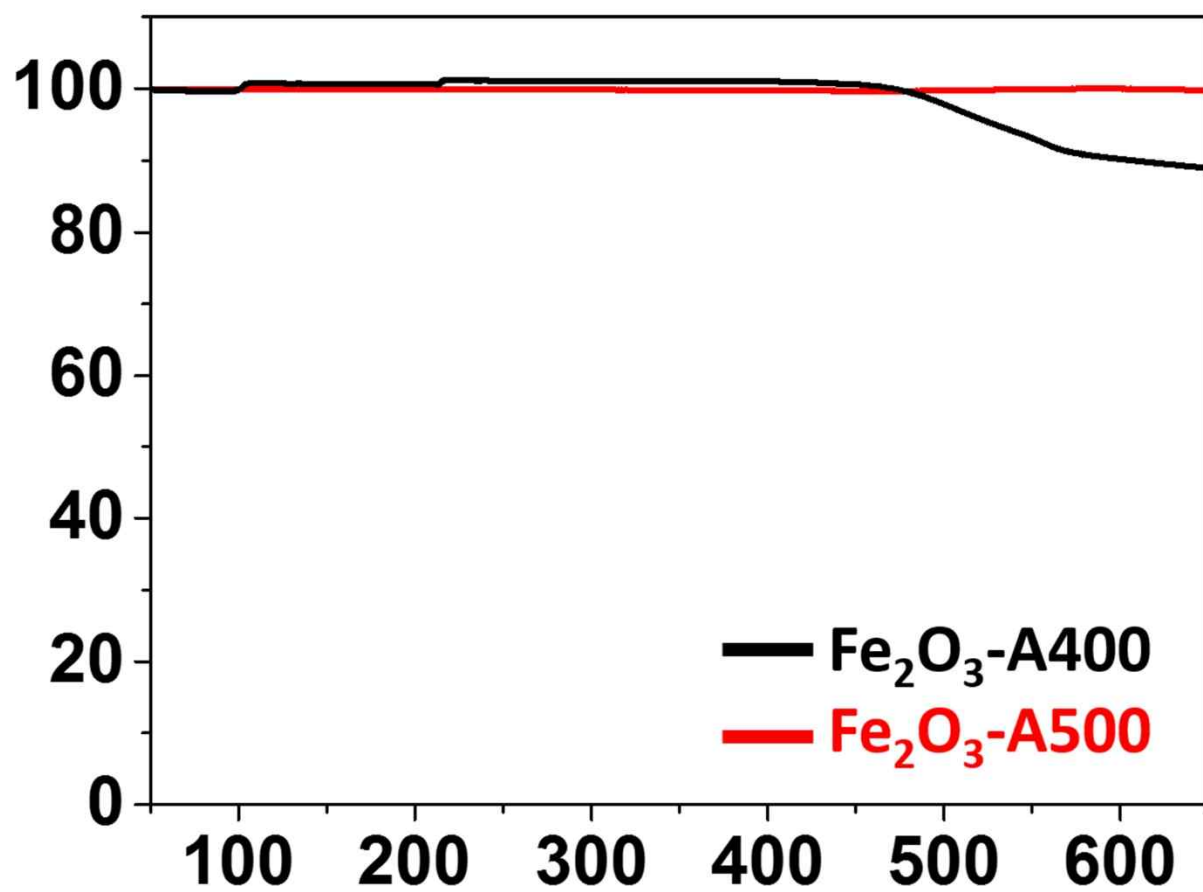


Fig. S6 TGA curves of Fe₂O₃-A400 and -A500 rod clusters.

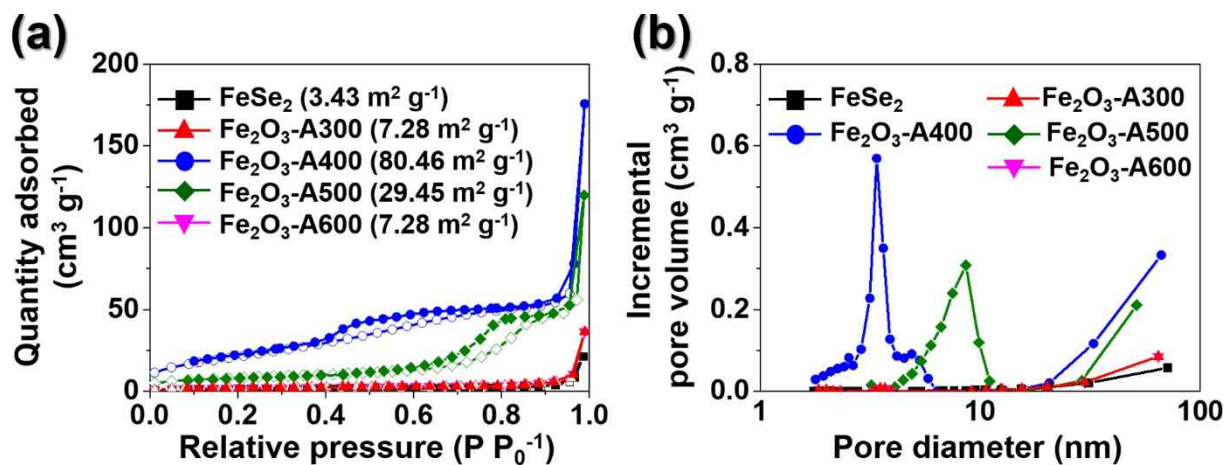


Fig. S7 (a) N₂ adsorption and desorption isotherms and (b) BJH pore size distributions of FeSe₂, Fe₂O₃-A300, -A400, -A500, and -A600 rod clusters.

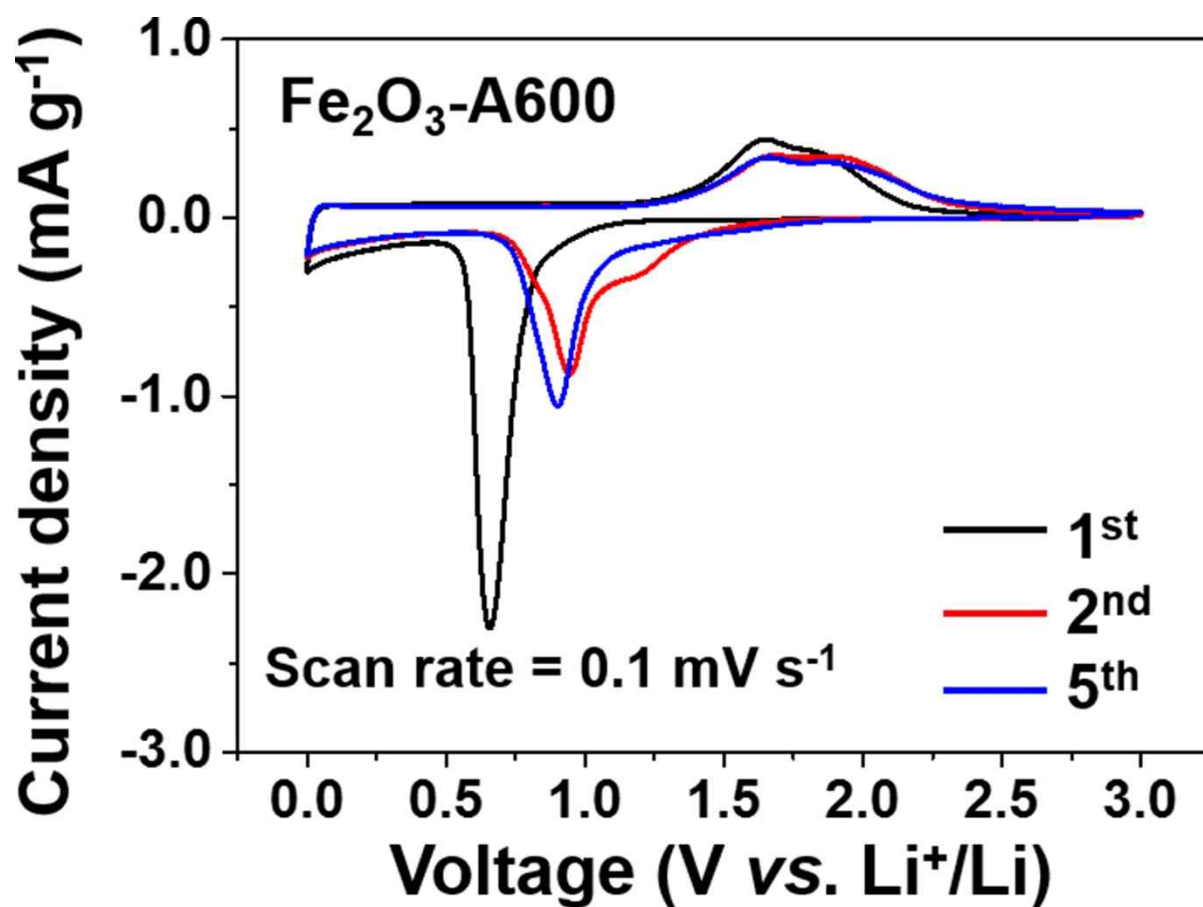


Fig. S8 CV curves of Fe₂O₃-A600 rod clusters obtained at 0.1 mV s⁻¹ in the potential range of 0.001 – 3.0 V for the first, second, and fifth cycles.

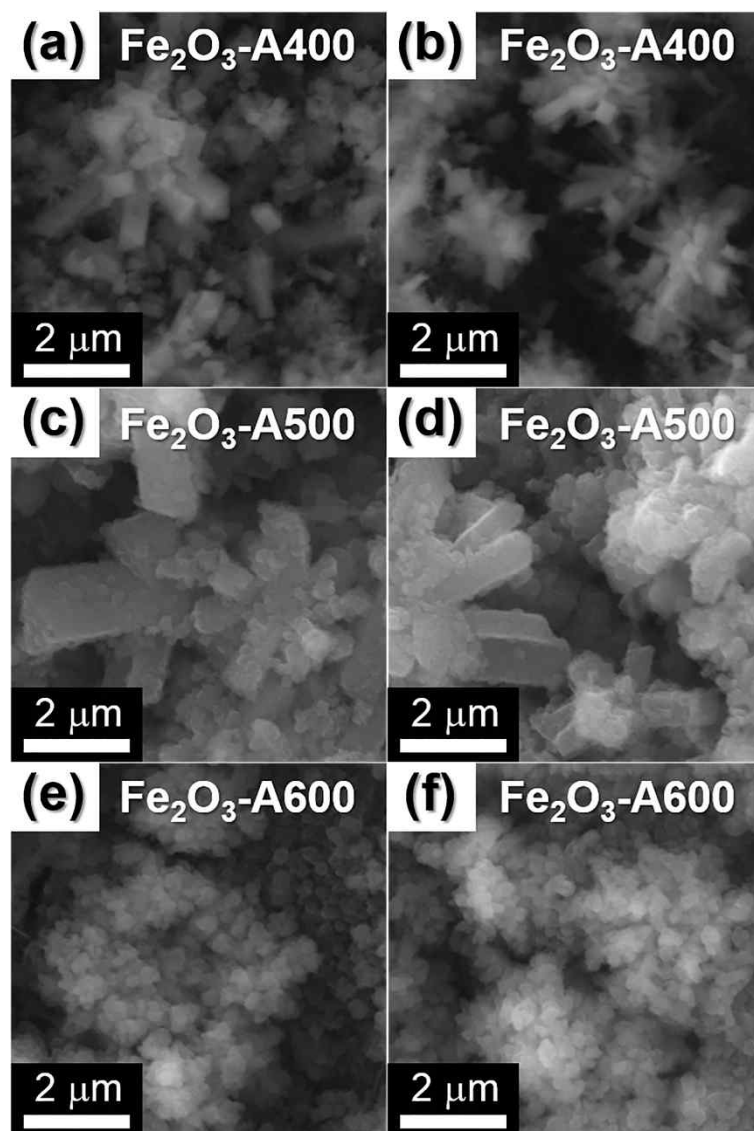
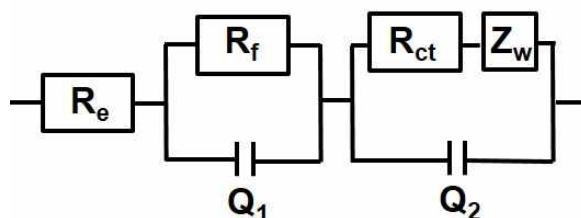


Fig. S9 SEM images of (a, b) Fe₂O₃-A400, (c, d) -A500, and (e, f) -A600 rod clusters after 100 cycles.

Equivalent circuit model



R_e : the electrolyte resistance, corresponding to the intercept of high frequency semicircle at Z' axis

R_f : the SEI layer resistance corresponding to the high-frequency semicircle

Q_1 : the dielectric relaxation capacitance corresponding to the high-frequency semicircle

R_{ct} : the denote the charger transfer resistance related to the middle-frequency semicircle

Q_2 : the associated double-layer capacitance related to the middle-frequency semicircle

Z_w : the Li-ion diffusion resistance

Fig. S10 Randle-type equivalent circuit model used for AC impedance fitting.

Table S1. Chemical composition of FeSe₂, and Fe₂O₃-A300, -A400, -A500, and A600 rod clusters (based on the EDX quantitative data)

Samples	Fe (wt %)	Se (wt %)	O (wt %)	Total
FeSe ₂ rod clusters	28.5	71.2	0.3	100
Fe ₂ O ₃ -A300	44.1	38.4	17.5	100
Fe ₂ O ₃ -A400	65.0	7.7	27.3	100
Fe ₂ O ₃ -A500	69.4	1.4	29.2	100
Fe ₂ O ₃ -A600	70.2	0.0	29.8	100

Table S2. Electrochemical properties of the Fe₂O₃ materials with various structures as anode materials for LIBs.

Materials	Voltage range [V]	Current rate [A g ⁻¹]	Discharge capacity after cycling [mA h g ⁻¹]	Rate capability [mA h g ⁻¹]/[A g ⁻¹]	Ref
<i>Porous Fe₂O₃ rod clusters</i>	<i>0.001 – 3.0</i>	<i>1.0</i>	<i>1381 (200th)</i>	<i>745 (10.0 A g⁻¹)</i>	<i>Our work</i>
Hollow Fe ₂ O ₃ spheres	0.05-3.0	0.2	710 (100 th)	-	1
Hierarchical hollow spheres composed of Fe ₂ O ₃ nanosheets	0.01-3.0	0.5	815 (200 th)	330 (5.0 A g ⁻¹)	2
Hierarchical Fe ₂ O ₃ microboxes	0.005-3.0	0.2	945 (30 th)	-	3
Hollow Fe ₂ O ₃ nanospheres	0.01-3.0	0.25	490 (50 th)	-	4
Hollow Fe ₂ O ₃ nanobarrels	0.01-3.0	0.5	916 (100 th)	403 (10.0 A g ⁻¹)	5
Multi-shelled hollow Fe ₂ O ₃ spheres	0.05-3.0	0.4	861 (50 th)	294 (4.0 A g ⁻¹)	6
Graphene-constructed hollow Fe ₂ O ₃ spheres	0.01-3.0	0.1	950 (50 th)	640 (1.0 A g ⁻¹)	7
Carbon coated hollow Fe ₂ O ₃ sphere	0.01-3.0	0.3	950 (100 th)	-	8
Fe ₂ O ₃ nanorods	0.005-3.0	0.5	970 (100 th)	300 (5.0 A g ⁻¹)	9
Spindle-like Fe ₂ O ₃	0.01-3.0	0.2	911 (50 th)	424 (10.0 A g ⁻¹)	10
Fe ₂ O ₃ nanoparticle-loaded carbon nanofibers	0.05-2.8	0.05	488 (75 th)	288 (0.5 A g ⁻¹)	11
Fe ₂ O ₃ nano-assembled spindles	0.005-3.0	0.1	~900 (40 th)	430 (1.0 A g ⁻¹)	12

References

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